TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK982

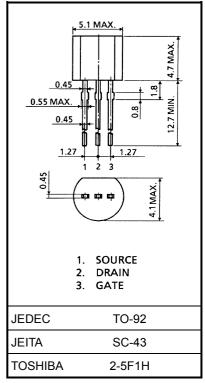
High Speed Switching Applications Analog Switch Applications Interface Applications

- Excellent switching times: ton = 14 ns (typ.)
- High forward transfer admittance: $|Y_{fs}| = 100 \text{ mS (min)}$ @ $I_D = 50 \text{ mA}$
- Low on resistance: $RDS(ON) = 0.6 \Omega \text{ (typ.)} @ ID = 50 \text{ mA}$
- Enhancement-mode
- Complementary to 2SJ148

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	200	mA	
	Pulse	I _{DP}	800		
Drain power dissipation		P _D	400	mW	
(Ta = 25°C)		гD	400		
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Unit: mm



Weight: 0.21 g (typ.)



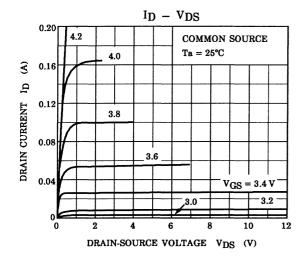
Electrical Characteristics (Ta = 25°C)

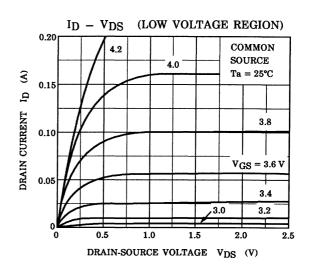
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off current		I _{DSS}	V _{DS} = 60 V, V _{GS} = 0		_	10	μΑ
Drain-source brea	akdown voltage	V (BR) DSS	$I_D = 1$ mA, $V_{GS} = 0$	60	_	_	V
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2	_	3.5	V
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 50 mA	100	_	_	mS
Drain-source ON	resistance	R _{DS} (ON)	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	0.6	1.0	Ω
Drain-source ON voltage		V _{DS (ON)}	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	30	50	mV
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	55	65	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	13	18	pF
Output capacitance		C _{oss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		40	50	pF
Switching time	Rise time	t _r	$I_{D} = \underbrace{100 \text{ mA}}_{VOUT}$ $V_{DD} = \underbrace{30 \text{ V}}_{VOUT}$	_	8	_	
	Turn-on time	t _{on}		_	14	_	ns
	Fall time	t _f		_	35	_	
	Turn-off Time	t _{off}	$\begin{aligned} &V_{IN}; \ t_r, \ t_f < 5 \ \text{ns} \\ &D.U \leq 1\% \ (Z_{out} = 50 \ \Omega) \end{aligned}$	_	75	_	

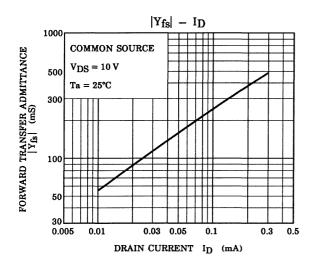
Note: This transistor is the electrostatic sensitive device.

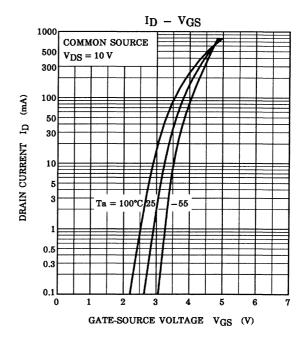
Please handle with caution.

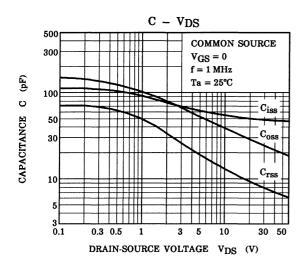
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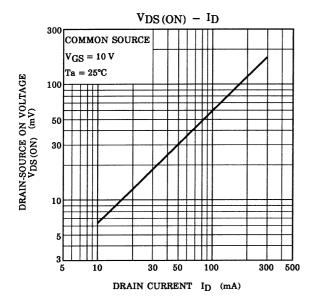


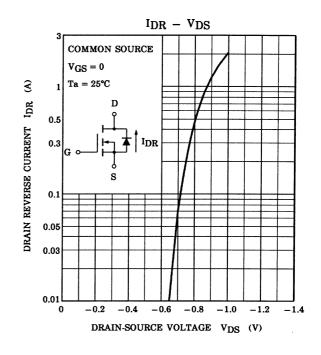


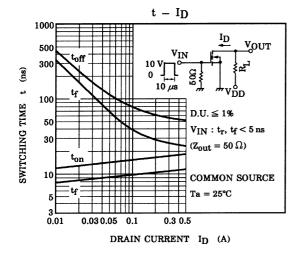


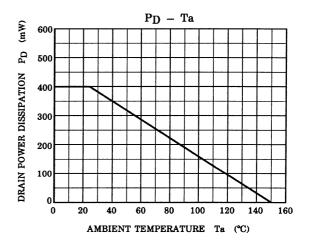


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